

SD3421/5421

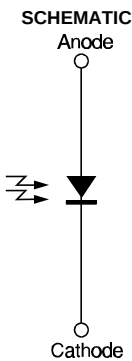
Silicon PIN Photodiode

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)						
PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Light Current SD3421-002 SD5421-002	I _L	10.0 40.0			μA	V _R =20 V H=5 mW/cm ² (1)
Dark Current	I _D			20	nA	V _R =20 V H=0
Reverse Breakdown Voltage	V _{BR}	75			V	I _R =10 μA
Angular Response (2) SD3421 SD5421	Ø		90 18		degr.	I _F =Constant
Rise And Fall Time	t _r , t _f		15		ns	V _R =20 V R _L =50 Ω

Notes
1. The radiation source is a tungsten lamp operating at a color temperature of 2870°K.
2. Angular response is defined as the total included angle between the half sensitivity points.

ABSOLUTE MAXIMUM RATINGS	
(25°C Free-Air Temperature unless otherwise noted)	
Cathode Anode Voltage	75 V
Power Dissipation	150 mW (1)
Operating Temperature Range	-55°C to 125°C
Storage Temperature Range	-65°C to 150°C
Soldering Temperature (10 sec)	260°C

Notes
1. Derate linearly from 25°C free-air temperature at the rate of 1.43 mW/°C.



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SWITCHING TIME TEST CIRCUIT

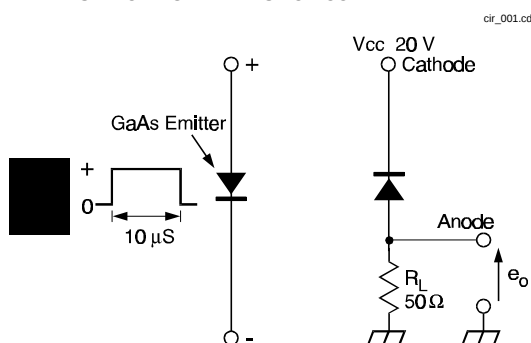
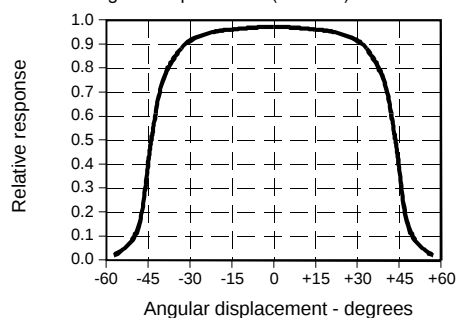


Fig. 1 Responsivity vs Angular Displacement (SD3421)



SWITCHING WAVEFORM

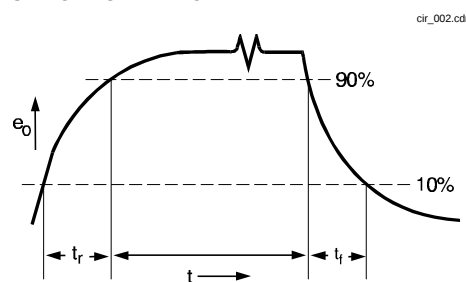


Fig. 2 Responsivity vs Angular Displacement (SD5421)

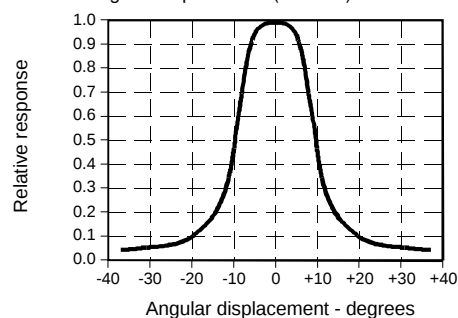


Fig. 3 Dark Current vs Temperature

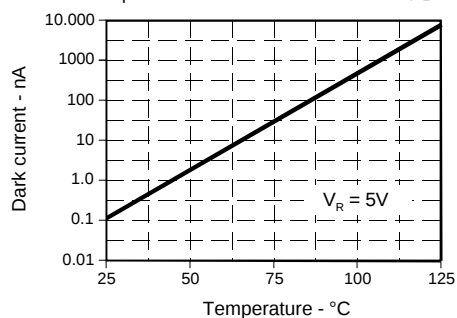
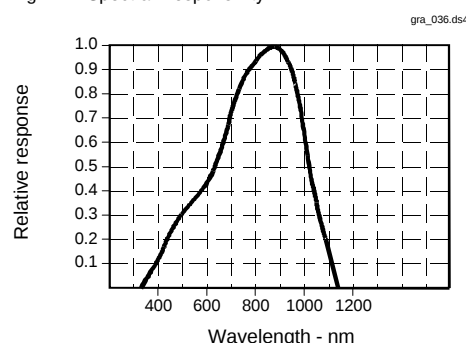


Fig. 4 Spectral Responsivity



All Performance Curves Show Typical Values

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